DECLARATION AND POWER OF ATTORNEY U.S.A.

ALL PATENTS, INCLUDING DESIGN FOR APPLICATION BASED ON PCT: PARIS CONVENTION; NON PRIORITY; OR PROVISIONAL APPLICATIONS

FOR ATTORNE ATTORENYS'					
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METHOD FOR M	ANUFACTURING MTJ C	ELL OF MAGNETIC RANDOM	ACCESS MEMORY
which is described and claim	ned in: PCT Internatio	nal Application No.	filed
X the attached specification	the specification	on in application Serial No.	filed
	(if applicable) ar	nd amended on	-
any amendment referred to a I acknowledge the duty to dis I hereby claim foreign priori certificate listed below and h of the application on which p	above. sclose information which is mat ty benefits under Title 35, Unit nave also identified below any f	erial to patentability as defined in Title ed States code, §119 (a)-(d) of any fo	ation, including the claims, as amended I 37, Code of Federal Regulations, §1.56. reign application(s) for patent or inventor or's certificate having a filing date befor the
Prior Foreign Application(s) 2002-42059	KR	18/07/2002	Priority Claimed
(Number)	(Country)	(Day/Month/Year Filed)	Yes . No
(Number)	(Country)	(Day/Month/Teal Flied)	ies . No
(Number)	(Country)	(Day/Month/Year Filed)	Yes No
(Number)	(Gountay)	(Day/Monthly real Filed)	
(Number)	(Country)	(Day/Month/Year Filed)	Yes No
I hereby claim the benefit un	der Title 35, United States Cod	e, §119(e) of any United States provision	onal application(s) listed below:
Application No.	Filing Date	Application No.	Filing Date
subject matter of each of the first paragraph of Title 35, defined in Title 37, Code of national or PCT international	e claims of this application is n United States Code, §112, act of Federal Regulation, §1.56 w I filing date of this application:	not disclosed in the prior United States knowledge the duty to disclose inform thich became available between the	lication(s) listed below and, insofar as to application in the manner provided by the nation which is material to patentability filing date of the prior application and the continuous patental panding abandoned).
	· ·	t the following attorneys (Registration	(Status: patented, pending, abandoned) No.) to prosecute this application, received therewith HARVEY B. JACOBSO
act on instruction from my age 20,851); JOHN CLARKE HOI	ent, and transact all business in LMAN (22,769); MARVIN R. ST	TERN (20,640); ALLEN S. MELSER (2	77,215); MICHAEL R. SLOBASKY (26,42 'OON S. HAM (45,307) and NATHANIEL

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I further declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment or both, under section 1001 of Title 18 of the United States Code; and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

SIGNATURE OF INVENTOR 201*	SIGNATURE OF INVENTOR 202*	SIGNATURE OF INVENTOR 203*		
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DATE June 10, 2003	DATE	DATE		

Additional inventors are named on separately numbered sheets attached hereto.

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